

EOGG6

PROGRAMME

SESSIONS AND TOPICS

SESSION 7 Chairs: Giuseppe Falini and Stéphane Veessler

Crystallization in Organic and Biological Systems

Advances in growth of organic, macromolecular and biomolecular crystals. Protein and polymer crystalline materials. Bio-mineralization and bio-inspired crystallization.

SESSION 8 Chairs: Heike Lorenz and Kevin Roberts

Industrial Crystallization, Technologies and Process Control

Crystallization for industrial applications. New equipment and technologies. Food, cosmetic, and pharmaceutical products.

SESSION 9 Chairs: Raffaella Lo Nigro and Dorota A. Pawlak

Novel Materials and Structures

New materials and structures with specific or improved properties and/or newly-designed applications. Inorganic and organic hybrid structures. Applications in areas of energy conversion, storage, magnetics, optoelectronics, quantum computation, nanoelectromechanical systems, and semiconductor electronics.

SESSION 10 Chairs: Christiane Frank-Rotsch and Evgeny Zharikov

New Methods and Techniques for Crystal Growth

Crystal growth under variety of external fields and extreme conditions – electric fields, magnetic fields, hyper and micro gravity, radiation, vibration, ultrasonic, high pressure, thermal and mechanical stress, etc.

SESSION 11 Chairs: Florinda da Costa and Ionut Enculescu

Advances in Observation and Characterization Methods

In-situ monitoring methods and analysis of physical, structural and chemical properties of crystals. Microscopy, spectroscopy, scattering, and other characterization techniques.

SESSIONS AND TOPICS

SESSION 1 *Chairs: Dimo Kashchiev and Elias Vlieg*

Fundamentals of Nucleation and Crystal Growth

Theory, modeling, and experiment.

SESSION 2 *Chairs: Thierry Duffar and Daniel Vizman*

Bulk Crystal Growth

Crystallization mechanisms, morphology, growth instabilities, crystallography. Growth technologies and process control.

SESSION 3 *Chairs: Knut Deppert and Michal Leszczynski*

Surfaces, Interfaces, Epitaxial Growth, Thin Films

Structure and properties of solid-vapor, solid-liquid and solid-solid interfaces and surface morphology. Physical, chemical, and technological aspects of thin film formation and epitaxial growth.

SESSION 4 *Chairs: Andreas Danilewsky and Bogdan Ranguelov*

Structural Defects and Impurities in Crystalline Materials

Mechanisms of defect formation in crystals, crystalline structure, physical properties, surface and bulk defects.

SESSION 5 *Chairs: Vladimir Dubrovskii and Michail Michailov*

Crystal Growth and Characterization of Nanostructures, Low-dimensional and Confined Systems

Nanoparticles, quantum dots, nanowires, nanotubes, and other low dimensional structures. Fabrication by lithography, self-assembly, chemical synthesis, etc.

SESSION 6 *Chairs: Alberta Bonanni and Linda Pastero*

Crystallization of Inorganic Materials

Growth of advanced inorganic materials. Crystallization in solid-vapor, solid-liquid and solid-solid systems. Crystalline structure, and physical properties. Mesocrystals and colloidal systems.

16.09.2018 (SUN)

14:00–20:00

REGISTRATION – Riviera Beach Hotel – New Event Reception desk

18:00–20:00

WELCOME reception ECCG6 – Riviera Terrace

17.09.2018 (MON)

08:45–09:15

Opening ceremony – Hall „Riviera“

09:15–10:10

Tom Leysens
Application philosophies for multi-component crystal systems
Plenary lecture
Hall „Riviera“

10:10–10:20

Parallel sessions

Session 01,
 Chairs: *Dimo Kashchiev, Elias Vlieg*
Hall „Riviera“

Session 09,
 Chairs: *Raffaella Lo Nigro, Dorota Pawlak*
Hall „Conference“

10:20–10:55

Romain Grossier
Crystal nucleation in microdroplets
S01–I1

Roberto Fornari
*Thin films of epsilon-Ga₂O₃ polymorph:
 doping, properties and applications*
S09–I1

10:55–11:15

Coffee break

11:15–11:50

Frank Glas
*The driving force for truncation formation at the
 liquid–solid interface during nanowire growth*
S01–I2

Martin Valldor
Anti–Perovskite Lithium Battery Cathodes
S09–I2

11:50–12:25

Wim Noorduin
*Controlling nucleation, growth and form of bio–
 inspired minerals*
S01–I3

Dumitru Dumcenco
*Growth of van der Waals magnetic
 semiconductor materials*
S09–O1 **ends 12:15**

12:25–13:00

Luis Zepeda-Ruiz
*Nucleation and crystallization kinetics in simple
 melts: modeling basic phenomena*
S01–I4

Ionut Enculescu
Nanowire based electronic devices
S09–O2 **ends 12:50**

13:00–13:25	<p>Marcel Rost <i>When vapor deforms metal: Thermodynamics of deposition flux dependent intrinsic film stress</i> S01–01</p>	<p>Raffaella Lo Nigro <i>Structural and electrical properties of epitaxial AlN films on GaN grown by low temperature plasma-assisted atomic layer deposition</i> S09–03</p>
13:25–16:00	Lunch break	
16:00–16:25	<p>Noushin Shahidzadeh <i>Hopper growth of salt crystals</i> S01–03</p>	<p>Dmitry Dominskiy <i>Molecular self-doping controls luminescent and charge transport properties in organic semiconductor single crystals</i> S09–04</p>
16:25–16:50	<p>Ondrej Cernohorsky <i>Hydrothermal growth of ZnO nanorods: modeling of supersaturation in batch and flow reactors</i> S01–04</p>	<p>Dorota Pawlak <i>Plasmonic materials/metamaterials and other novel photonic materials obtained by crystal growth</i> S09–05</p>
16:50–17:10	Coffee break	
17:10–17:40	<p>Koichi Kakimoto <i>Tribute to Michael Schieber</i> Memorial lecture, Hall „Riviera“</p>	
17:40–17:50	Parallel sessions	
	<p>Session 08, Chairs: Heike Lorenz, Kevin Roberts Hall „Riviera“</p>	<p>Session 10, Chairs: Christiane Frank–Rotsch, Evgeny Zharikov Hall „Conference“</p>
17:50–18:25	<p>Stéphane Veessler <i>Microfluidics crystallization in tubes (nucleation, optimization, screening...)</i> S08–11</p>	<p>Vladimir Golyshev <i>AHP technology: controlled crystal growth from melt</i> S10–11</p>
18:25–19:00	<p>Adrian Flood <i>New developments in temperature cycle induced deracemization</i> S08–12</p>	<p>Zbigniew Galazka <i>New methods for growing thermally unstable oxide single crystals from melt</i> S10–12</p>

19:00–19:25	<p>Pablo Soladana <i>Crystal growth and nucleation in continuous microfluidic crystallization platform</i> S08–01</p>	<p>Sanne Granneman <i>Magnetic field induced polymorph selection</i> S10–01</p>
19:25–21:00	Dinner break	
21:00–23:00	First POSTER SESSION – Hall „Seminar“	
	Session 01, Session 03, Session 08, Session 09, Session 10, Session 11	

18.09.2018 (TUE)

09:00–09:55	<p>Fiona Meldrum <i>Controlling Crystallisation using Confinement and Surface Topography</i> Plenary lecture, Hall „Riviera“</p>	
09:55–10:05	Parallel sessions	
	<p>Session 03, <i>Chairs: Knut Deppert, Michal Leszczynski</i> Hall „Riviera“</p>	<p>Session 02, <i>Chairs: Thierry Duffar, Daniel Vizman</i> Hall „Conference“</p>
10:05–10:40	<p>Jonas Johansson <i>Understanding the composition of epitaxially grown ternary III–Vnanowires</i> S03–I1</p>	<p>Alexandre Tallaire <i>Controlling defects during the growth of large size diamond single crystals by plasma assisted chemical vapour deposition</i> S02–I1</p>
10:40–11:15	<p>Yu Liu <i>Semiconductor /ferromagnetic insulator InAs/ EuS epitaxy</i> S03–I2</p>	<p>Biao Wang <i>The automatic growth system with in–situ interface detection and energy–saving features</i> S02–I2</p>
11:15–11:35	Coffee break	
11:35–12:10	<p>Jesus Zuniga Perez <i>Growth of semipolar GaN by MOVPE: from patterned substrates to high–quality templates</i> S03–I3</p>	<p>Stefan Ecklebe <i>Control of the VGF Process I: Feedforward Control and Flatness Based State Feedback</i> S02–I3</p>
12:10–12:35	<p>Stefano Curitto <i>Dynamics of Si surface nanostructures under electromigration</i> S03–O1</p>	<p>Andrea Zappettini <i>New advancements towards spectroscopic grade CdZnTe material by the boron oxide encapsulated vertical Bridgman method</i> S02–O1</p>

12:35–13:00	<p>Dmitry Rogilo <i>Concentration distribution of adatoms and surface vacancies on extremely wide Si(111) terraces during sublimation</i> S03–02</p>	<p>Maria Tsoutsouva <i>Growth kinetics and defects associated with the formation of a random grain boundary during Si directional solidification</i> S02–02</p>
13:00–13:25	<p>Alexandr Nikiforov <i>Elastically stressed pseudomorphic GeSiSn film growth</i> S03–03</p>	<p>Armands Krauze <i>3D modeling of growth ridge and edge facet formation in <100> FZ silicon crystal growth process</i> S02–03</p>
13:25–15:50	Lunch break	
14:30 – 15:50	ENCG Members – ENCG Council Meeting Hall „Conference“	
15:50–16:00	All together photo	
16:00–16:45	<p>Michail Michailov <i>Iwan N. Stranski and the Sofia school of crystal growth</i> Memorial lecture, Hall „Riviera“</p>	
16:45–17:00	Parallel sessions	
17:00–17:25	<p>Vladimir Tassev <i>Heteroepitaxy of nonlinear optical material for frequency conversion of laser sources in the mid and longwave IR</i> S03–04</p>	<p>Frank M. Kiessling <i>Technology Development of High–Purity Germanium Crystals for Detectors to Be Used in GERDA and LEGEND</i> S02–04</p>
17:25–17:50	<p>Mohsin Qazi <i>Creeping of salt solutions</i> S03–05</p>	<p>Iaroslav Gerasymov <i>Methods for luminescence decay control in YAG–based crystals</i> S02–05</p>
17:50–18:10	Coffee break	
	<p>Session 11, Chairs: Florinda Costa, Ionut Enculescu Hall „Riviera“</p>	
18:10–18:45	<p>Cristian Teodorescu <i>Photoelectron spectroscopy and spectro–microscopy techniques in studies of surfaces of ferroelectric materials</i> S11–11</p>	<p>Martin Klejch <i>Growth of radiation hard PWO crystals in open furnaces</i> S02–06</p>

18:45–19:10	<p>Louiza Ejim <i>Characterization of Continuous Crystallization Deposition on Surfaces</i> S11–O1</p>	<p>Mathias Velazquez <i>Czochralski growth of Li₂MoO₄ crystals for the scintillating bolometers used in the rare events searches</i> S02–O7</p>
	<p>Session 04, Chairs: <i>Andreas Danilewsky, Bogdan Ranguelov</i> Hall „Riviera“</p>	<p>Session 07, Chairs: <i>Giuseppe Falini, Stephane Veesler</i> Hall „Conference“</p>
19:10–19:35	<p>Per Persson <i>The application of advanced electron microscopy in 3D and 2D materials</i> S04–I1</p>	<p>Dominique Maes <i>Do protein crystals and aggregates go with the flow?</i> S07–I1</p>
19:35–21:00	Dinner break	
21:00–23:00	Second POSTER SESSION – Hall „Seminar“	
	Session 02, Session 04, Session 05, Session 06, Session 07	

19.09.2018 (WED)

	<p>Session 07, Chairs: <i>Giuseppe Falini, Stephane Veesler</i> Hall „Riviera“</p>	<p>Session 05, Chairs: <i>Michail Michailov, Vladimir Dubrovskii</i> Hall „Conference“</p>
09:00–09:35	<p>Damir Kralj <i>TInteractions between calcite and selected oligopeptides and their functional derivatives</i> S07–2</p>	<p>Joan Redwing <i>Epitaxy of 2D transition metal dichalcogenides</i> S05–I1</p>
09:35–10:00	<p>Linda Pastero <i>Interactions at the surfaces in bio-apatites</i> S07–O1</p>	<p>Martin Groenke <i>Crystal growth of 2D honeycomb transition metal halide MX₃ nanosheets by chemical vapor transport (CVT)</i> S05–O1</p>
10:00–10:35	<p>Jose Gavira <i>Protein crystallization in hydrogels, What for?</i> S07–O2</p>	<p>Michael Tringides <i>Non–classical, explosive nucleation and collective, multi–atom diffusion in epitaxial metallic films</i> S05–I2</p>
	<i>ends 10:25</i>	

10:35–11:00	<p>Yi-Yeoun Kim <i>Bio-Inspired Approaches to Creating Functional Nanocomposite Crystals</i> S07–03</p>	<p>Nickolay Sibirev <i>Comparison of gold and silver catalyzed growth of GaAs nanowires</i> S05–02</p>
11:00–11:20	Coffee break	
	<p>Session 04, Chairs: <i>Andreas Danilewsky, Bogdan Ranguelov</i> Hall „Riviera“</p>	
11:20–11:55	<p>Helmut Klapper <i>The generation of growth dislocations by inclusions and growth-face damages: an experimental study</i> S04–I2</p>	<p>Simon Watkins <i>Novel methods for the growth and characterization of single nanowire semiconductor structures</i> S05–I3</p>
		<p>Session 06, Chairs: <i>Alberta Bonanni, Linda Pastero</i> Hall „Conference“</p>
11:55–12:30	<p>Sergei Sitnikov <i>Real-time observation of self-interstitial transfer onto an atomically smooth Si(111) surface at gold diffusion into the volume</i> S04–O1 <i>ends 12:20</i></p>	<p>Denis Gebauer <i>Amorphous intermediates in crystallization: from polyamorphism to crystal growth and superstructure formation</i> S06–I1</p>
12:30–13:05	<p>Carmen Stelian <i>Effect of the solid–liquid interface shape on the colony type microstructure of directionally solidified Al₂O₃/Y₃Al₅O₁₂/ZrO₂ eutectic composite</i> S04–O2 <i>ends 12:55</i></p>	<p>Henk Huinink <i>Utilizing solid–solid transitions in crystal hydrates for heat storage</i> S06–O1</p>
13:05–15:00	Lunch break	
	<p>Session 01, Chairs: <i>Dimo Kashchiev, Elias Vlieg</i> Hall „Riviera“</p>	
15:00–15:35	<p>Michael Gonik <i>Axial segregation in crystal growth from a thin melt layer</i> S01–02 <i>ends 15:25</i></p>	<p>Michał Boćkowski <i>Bulk growth of GaN – status, perspectives and trends</i> S06–I2</p>

15:35–16:00	<p style="text-align: center;">Svetlozar Ivanov <i>Understanding the initial stages of Si electrode- position in ionic liquid based electrolytes</i> S01–05</p>	<p style="text-align: center;">Emel Akyol <i>The effects of avocado leaves extract on calcium oxalate monohydrate growth: An in vitro study</i> S06–02</p>
16:00–16:25	<p style="text-align: center;">Matias Velazquez <i>Multiscale characterization of the point defect disorder in high–temperature solution grown crystals of the new phase Sr6Tb0.94Fe1.06 (BO3)6</i> S06–03</p>	
16:25–16:50	<p style="text-align: center;">Closing, Announcement of ECCG7 and ESCG3</p>	
18:45–20:00	<p style="text-align: center;">Dinner break</p>	
20:00–24:00	<p style="text-align: center;">Farewell Party – Riviera beach hotel (Signing up at ECCG6 organizers is mandatory) ECCG6 Awards</p>	

LEGEND TIME	
Plenary lectures	45' + 10'
Invited lectures	30' + 5'
Oral presentations	20' + 5'